

**Attorney Docket No.: 06484.0074**

SN#09740016

### ABSTRACT OF THE DISCLOSURE

An electrostatic discharge (ESD) protection device includes a semiconductor layer, a source region formed in the layer, a drain region formed in the layer, a channel region in the layer between the source and drain regions, and a gate over the channel region. A plurality of current divider segments are distributed on the drain region and extend between the gate and drain contacts. The segments can be formed of polysilicon or a field oxide.

54 - B      S.R.L.      Dec. 14, 2000  
                  CH.L      Dec. 14, 2000  
                  WFC      Dec 14, 2000  
                  W.Y.L.      Dec 16, 2000